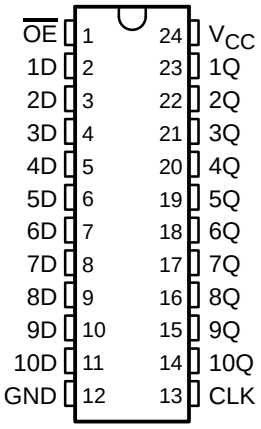
- ***EPIC***™ **(Enhanced-Performance Implanted CMOS) Submicron Process**
- **Typical $V_{OLP}$ (Output Ground Bounce) < 0.8 V at $V_{CC}$ = 3.3 V, $T_A$ = 25°C**
- **Typical $V_{OHV}$ (Output $V_{OH}$ Undershoot) > 2 V at $V_{CC}$ = 3.3 V, $T_A$ = 25°C**
- **Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V $V_{CC}$)**
- **Power Off Disables Inputs/Outputs, Permitting Live Insertion**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages**

**DB, DW, OR PW PACKAGE**
**(TOP VIEW)**




## description

This 10-bit bus-interface flip-flop is designed for 2.7-V to 3.6-V $V_{CC}$ operation.

The SN74LVC821A features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

The ten flip-flops are edge-triggered D-type flip-flops. On the positive transition of the clock (CLK) input, the device provides true data at the Q outputs.

A buffered output-enable ($\overline{OE}$) input can be used to place the ten outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

$\overline{OE}$ does not affect the internal operations of the latch. Previously stored data can be retained or new data can be entered while the outputs are in the high-impedance state.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V/5-V system environment.

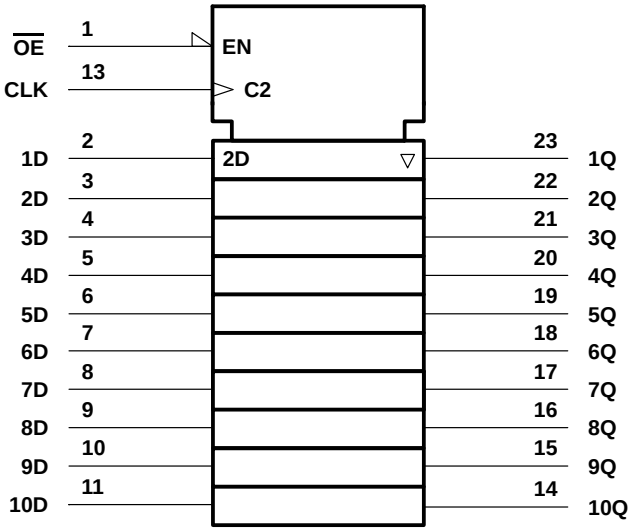
To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to $V_{CC}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74LVC821A is characterized for operation from –40°C to 85°C.

**FUNCTION TABLE**
**(each flip-flop)**

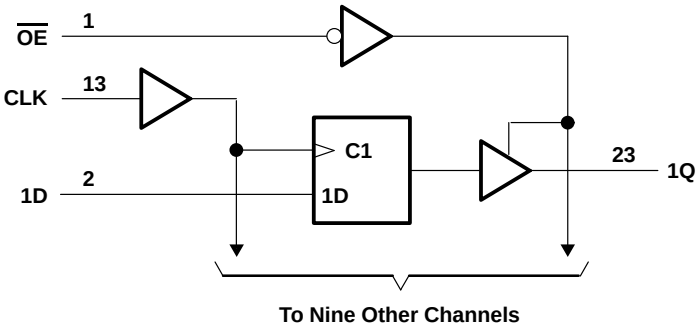
| INPUTS | | | OUTPUT |
|---|---|---|---|
| $\overline{OE}$ | CLK | D | Q |
| L | ↑ | H | H |
| L | ↑ | L | L |
| L | H or L | X | $Q_0$ |
| H | X | X | Z |

## logic symbol†




† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

## logic diagram (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$ . . . . . –0.5 V to 6.5 V
Input voltage range, $V_I$ (see Note 1) . . . . . –0.5 V to 6.5 V
Voltage range applied to any output in the high-impedance or power-off state, $V_O$ (see Note 1) . . . . . –0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, $V_O$ (see Notes 1 and 2) . . . . . –0.5 V to $V_{CC}$ + 0.5 V
Input clamp current, $I_{IK}$ ($V_I$ < 0) . . . . . –50 mA
Output clamp current, $I_{OK}$ ($V_O$ < 0 or $V_O$ > $V_{CC}$) . . . . . ±50 mA
Continuous output current, $I_O$ ($V_O$ = 0 to $V_{CC}$) (see Note 2) . . . . . ±50 mA
Continuous current through $V_{CC}$ or GND . . . . . ±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package . . . . . 104°C/W
DW package . . . . . 81°C/W
PW package . . . . . 120°C/W
Storage temperature range, $T_{stg}$ . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The value of $V_{CC}$ is provided in the recommended operating conditions table.
3. The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions (see Note 4)

| | | | MIN | MAX | UNIT |
|---|---|---|---|---|---|
| $V_{CC}$ | Supply voltage | Operating | 2 | 3.6 | V |
| | | Data retention only | 1.5 | | |
| $V_{IH}$ | High-level input voltage | $V_{CC}$ = 2.7 V to 3.6 V | 2 | | V |
| $V_{IL}$ | Low-level input voltage | $V_{CC}$ = 2.7 V to 3.6 V | | 0.8 | V |
| $V_I$ | Input voltage | | 0 | 5.5 | V |
| $V_O$ | Output voltage | High or low state | 0 | $V_{CC}$ | V |
| | | 3 state | 0 | 5.5 | |
| $I_{OH}$ | High-level output current | $V_{CC}$ = 2.7 V | | –12 | mA |
| | | $V_{CC}$ = 3 V | | –24 | |
| $I_{OL}$ | Low-level output current | $V_{CC}$ = 2.7 V | | 12 | mA |
| | | $V_{CC}$ = 3 V | | 24 | |
| $\Delta t/\Delta v$ | Input transition rise or fall rate | | 0 | 10 | ns/V |
| $T_A$ | Operating free-air temperature | | –40 | 85 | °C |

NOTE 4: Unused inputs must be held high or low to prevent them from floating.

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | $V_{CC}$ | MIN | TYP† | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|
| $V_{OH}$ | | $I_{OH}$ = –100 μA | | 2.7 V to 3.6 V | $V_{CC}$–0.2 | | | V |
| | | $I_{OH}$ = –12 mA | | 2.7 V | 2.2 | | | |
| | | | | 3 V | 2.4 | | | |
| | | $I_{OH}$ = –24 mA | | 3 V | 2.2 | | | |
| $V_{OL}$ | | $I_{OL}$ = 100 μA | | 2.7 V to 3.6 V | | | 0.2 | V |
| | | $I_{OL}$ = 12 mA | | 2.7 V | | | 0.4 | |
| | | $I_{OL}$ = 24 mA | | 3 V | | | 0.55 | |
| $I_I$ | | $V_I$ = 0 to 5.5 V | | 3.6 V | | | ±5 | μA |
| $I_{off}$ | | $V_I$ or $V_O$ = 5.5 V | | 0 | | | ±10 | μA |
| $I_{OZ}$ | | $V_O$ = 0 to 5.5 V | | 3.6 V | | | ±10 | μA |
| $I_{CC}$ | | $V_I$ = $V_{CC}$ or GND | $I_O$ = 0 | 3.6 V | | | 10 | μA |
| | | 3.6 V ≤ $V_I$ ≤ 5.5 V‡ | | | | | 10 | |
| $\Delta I_{CC}$ | | One input at $V_{CC}$ – 0.6 V, | Other inputs at $V_{CC}$ or GND | 2.7 V to 3.6 V | | | 500 | μA |
| $C_i$ | Control | $V_I$ = $V_{CC}$ or GND | | 3.3 V | | 5 | | pF |
| | Data | | | | | 4 | | |
| $C_o$ | | $V_O$ = $V_{CC}$ or GND | | 3.3 V | | 7 | | pF |

† All typical values are at $V_{CC}$ = 3.3 V, $T_A$ = 25°C.
‡ This applies in the disabled state only.

### timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| | | $V_{CC}$ = 3.3 V ± 0.3 V | | $V_{CC}$ = 2.7 V | | UNIT |
|---|---|---|---|---|---|---|
| | | MIN | MAX | MIN | MAX | |
| $f_{clock}$ | Clock frequency | 0 | 150 | 0 | 150 | MHz |
| $t_w$ | Pulse duration, CLK high or low | 3.3 | | 3.3 | | ns |
| $t_{su}$ | Setup time, data before CLK | 1.9 | | 1.9 | | ns |
| $t_h$ | Hold time, data after CLK | 1.5 | | 1.5 | | ns |

### switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

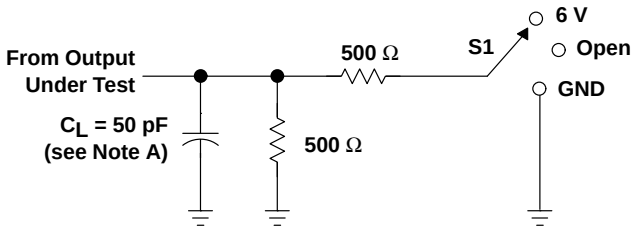
| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC}$ = 3.3 V ± 0.3 V | | $V_{CC}$ = 2.7 V | | UNIT |
|---|---|---|---|---|---|---|---|
| | | | MIN | MAX | MIN | MAX | |
| $f_{max}$ | | | 150 | | 150 | | MHz |
| $t_{pd}$ | CLK | Q | 2.2 | 7.3 | | 8.5 | ns |
| $t_{en}$ | $\overline{OE}$ | Q | 1.3 | 7.6 | | 8.8 | ns |
| $t_{dis}$ | $\overline{OE}$ | Q | 1.6 | 6.2 | | 6.8 | ns |
| $t_{sk(o)}$§ | | | | 1 | | | ns |

§ Skew between any two outputs of the same package switching in the same direction. This parameter is warranted but not production tested.

## operating characteristics, $V_{CC}$ = 3.3 V, $T_A$ = 25°C

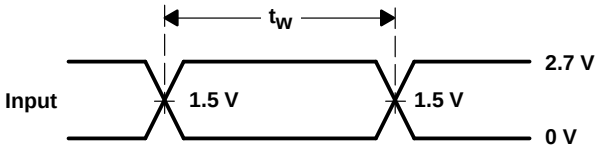
| PARAMETER | | | TEST CONDITIONS | | TYP | UNIT |
|---|---|---|---|---|---|---|
| $C_{pd}$ | Power dissipation capacitance per latch | Outputs enabled | $C_L$ = 0 pF, | f = 10 MHz | 65 | pF |
| | | Outputs disabled | | | 48 | |

## PARAMETER MEASUREMENT INFORMATION

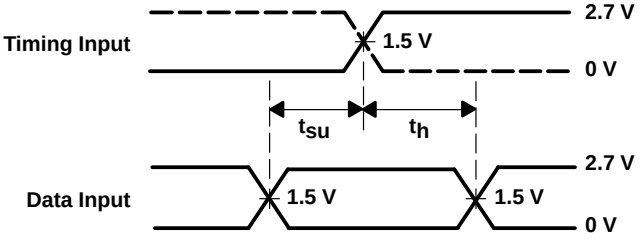



LOAD CIRCUIT

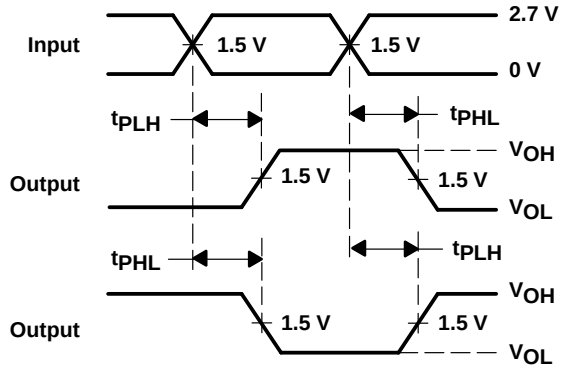
| TEST | S1 |
|---|---|
| $t_{pd}$ | Open |
| $t_{PLZ}/t_{PZL}$ | 6 V |
| $t_{PHZ}/t_{PZH}$ | GND |



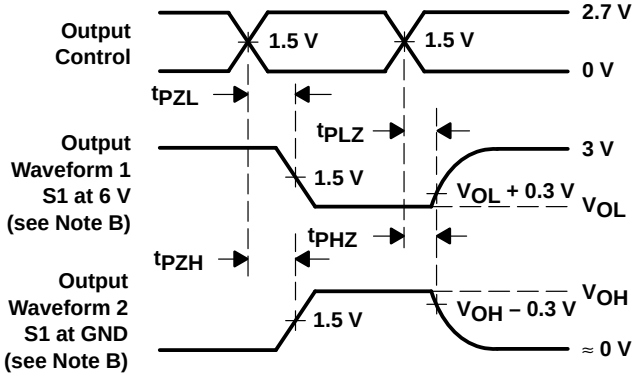

VOLTAGE WAVEFORMS
PULSE DURATION




VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS




VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ ≤ 2.5 ns, $t_f$ ≤ 2.5 ns.
D. The outputs are measured one at a time with one transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

**Figure 1. Load Circuit and Voltage Waveforms**

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